Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.253 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Features Provided:

Mounting hardware

Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

5.0 breakdown voltage, dc and 5.2 breakdown voltage, dc

Current Rating Per Characteristic:

490.00 milliamperes source cutoff current horsepower metric and 1.84 amperes repetitive peak forward current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Specification Data:

67177-103g3333 manufacturers specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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